

60V NPN SMALL SIGNAL TRANSISTOR IN SOT523

Features

- BV_{CEO} > 40V
- I_C = 200mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMBT3906T
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

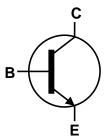
Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.002 grams (Approximate)

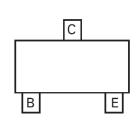
SOT523







Device Symbol



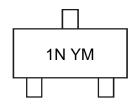
Pin-Out Top View

Ordering Information (Note 4)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMBT3904T-7-F	Active	AEC-Q101	1N	7	8	3,000
MMBT3904T-13-F	Active	AEC-Q101	1N	13	8	10,000

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



 $\begin{array}{l} 1N = Product\ Type\ Marking\ Code \\ YM = Date\ Code\ Marking \\ Y\ or\ \overline{Y} = Year\ (ex:\ A=2013) \\ M\ or\ \overline{M} = Month\ (ex:\ 9=September) \end{array}$

Date Code Key

Year	2013	2	014	2015	2016	2017	2018	2019	9 20	20 2	2021	2022	2023
Code	Α		В	С	D	Е	F	G	ŀ	1	1	J	K
Mont	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	Ic	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

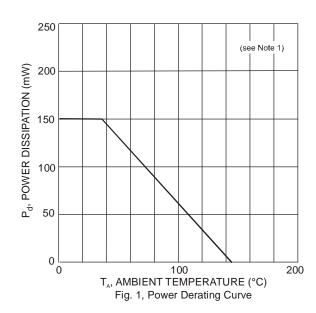
ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes

- 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information





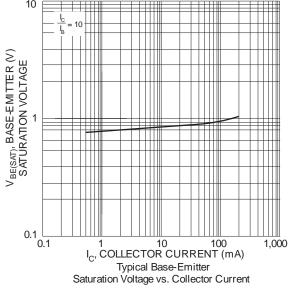
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

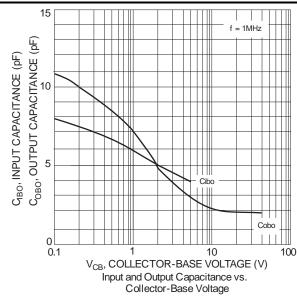
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	BV _{CBO}	60	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	40	_	V	$I_C = 1mA, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cutoff Current	ICEX	_	50	nA	$V_{CE} = 30V$, $V_{EB(OFF)} = 3V$
Base Cutoff Current	I _{BL}	_	50	nA	V _{CE} = 30V, V _{EB(OFF)} = 3V
ON CHARACTERISTICS (Note 7)					
DC Current Gain	h _{FE}	40 70 100 60 30	300 — —	_	$I_C = 100\mu A, V_{CE} = 1V$ $I_C = 1mA, V_{CE} = 1V$ $I_C = 10mA, V_{CE} = 1V$ $I_C = 50mA, V_{CE} = 1V$ $I_C = 100mA, V_{CE} = 1V$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.20 0.30	V	$I_C = 10$ mA, $I_B = 1$ mA $I_C = 50$ mA, $I_B = 5$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.65	0.85 0.95	٧	$I_C = 10mA, I_B = 1mA$ $I_C = 50mA, I_B = 5mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Сово	_	4	pF	$V_{CB} = 5V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C _{IBO}	_	8	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_{C} = 0$
Input Impedance	h _{IE}	1	10	kΩ	
Voltage Feedback Ratio	h _{RE}	0.5	8.0	x 10 ⁻⁴	$V_{CE} = 10V$, $I_C = 1mA$,
Small Signal Current Gain	h _{FE}	100	400	_	f = 1.0MHz
Output Admittance	h _{OE}	1	40	μS	
Current Gain-Bandwidth Product	f⊤	300	_	MHz	$V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz
Noise Figure	NF	_	5	dB	$V_{CC} = 5V, I_C = 100\mu A,$ $R_S = 1k\Omega, f = 1MHz$
SWITCHING CHARACTERISTICS					
Delay Time	t _D		35	ns	V _{CC} = 3V, I _C = 10mA,
Rise Time	t _R	_	35	ns	$V_{BE(OFF)} = -0.5V$, $I_{B1} = 1mA$
Storage Time	t _S		200	ns	V _{CC} = 3.0V, I _C = 10mA
Fall Time	t _F	_	50	ns	$I_{B1} = -I_{B2} = 1.0 \text{mA}$

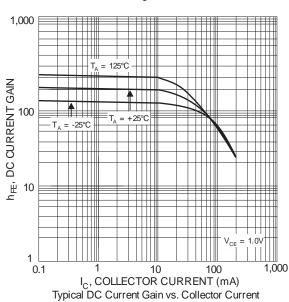
Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

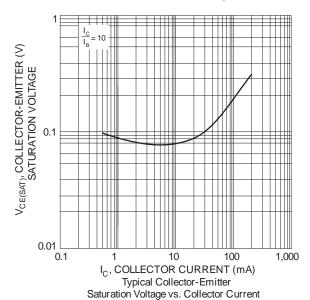


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)







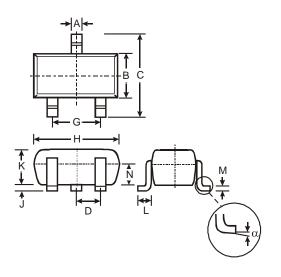




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

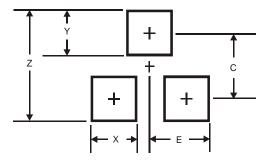


SOT523						
Dim	Min	Max	Тур			
Α	0.15	0.30	0.22			
В	0.75	0.85	0.80			
C	1.45	1.75	1.60			
D	_		0.50			
G	0.90	1.10	1.00			
Н	1.50	1.70	1.60			
J	0.00	0.10	0.05			
K	0.60	0.80	0.75			
L	0.10	0.30	0.22			
M	0.10	0.20	0.12			
N	0.45	0.65	0.50			
α	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Υ	0.51
С	1.3
Е	0.7



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